AUTOMOTIVE GRADE

RoHS³

HALOGEN

FREE

GREEN

(5-2008)



Solid Tantalum Surface Mount Capacitors TANTAMOUNT™ Molded Case, HI-TMP® High Temperature 150 °C, Automotive Grade



ADDITIONAL RESOURCES













PERFORMANCE / ELECTRICAL CHARACTERISTICS

www.vishav.com/doc?40215

Operating Temperature: -55 °C to +150 °C Capacitance Range: $0.33~\mu F$ to $220~\mu F$ Capacitance Tolerance: $\pm~10~\%, \pm~20~\%$ Voltage Rating: $6.3~V_{DC}$ to $50~V_{DC}$

Note

 For recommended voltage derating guidelines see "Typical Performance Characteristics"

FEATURES

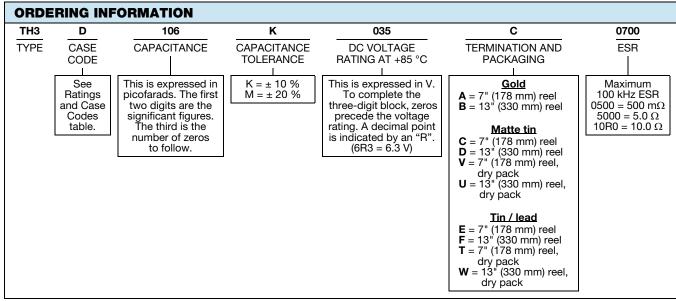
- Operating temperature up to 150 °C with 50 % voltage derating
- AEC-Q200 qualified
- 100 % surge current tested (B, C, D, E case sizes)
- RoHS-compliant terminations available: matte tin (all cases), gold (A, C, D, and E cases)
- Standard EIA 535BAAC case size (A through E)
- · Compliant terminations
- Moisture sensitivity level 1
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

Note

* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details

APPLICATIONS

- Automotive
- Industrial
- High temperature sensors



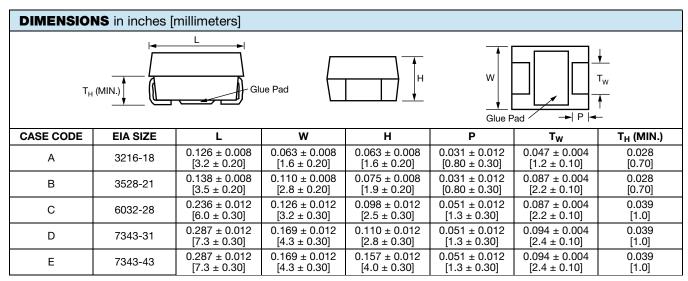
Notes

- We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size. Voltage substitutions will be marked with the higher voltage rating
- Dry pack as specified in J-STD-033

Revision: 21-Oct-2019







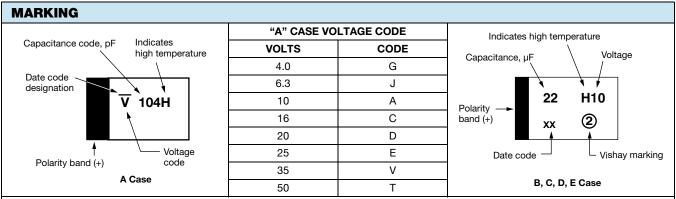
Note

Glue pad (non-conductive, part of molded case) is dedicated for glue attachment (as user option)

| RATINGS | AND CASE C | ODES | | | | | |
|---------|-------------------|---|--|--|-------------------------------------|---------------------------------|-------------------|
| μF | 6.3 V | 10 V | 16 V | 20 V | 25 V | 35 V | 50 V |
| 0.33 | | | | | | A (11.0) | |
| 0.47 | | | | | A (14.0) | | |
| 0.68 | | | | | | | |
| 1.0 | | | A (6.5) | A (5.9) | A (3.0, 5.2) / B (5.0) | A (6.6) / B (4.4) | C (3.3) |
| 1.5 | | | | | | B (4.2) / C (3.3) | |
| 2.2 | | A (4.6) | A (4.3) | A (5.9) / B (3.5) | A (5.2) / B (3.0) | B (2.5) / C (2.2) | |
| 3.3 | | | A (3.4) / B (3.0) | B (2.7) / C (3.7) | B (3.0) / C (2.0) | B (2.5, 3.5) / C (1.7) | D (1.7) |
| 4.7 | | A (2.9) / B (2.7) | A (2.9) / B (2.1) | A (5.0) / B (2.9, 1.9) / C (1.7) | A (5.0) / B (2.8) / C (1.6) | B (3.1) / C (1.3) / D (1.0) | C (1.5) / D (0.9) |
| 6.8 | | A (2.6) | A (2.6, 2.0) / B (1.8) / C (1.7) | | B (2.4) / C (1.4) | C (1.8) / D (0.9) | D (0.9) |
| 10 | A (3.4, 2.7) | A (3.4, 2.0) / B (1.8) / C (1.8, 1.7) | B (2.0) / C (1.4, 0.8) | C (1.1) | C (1.1) / D (0.9) | C (1.6) / D (0.25, 0.3, 0.7) | D (0.8) / E (0.5) |
| 15 | B (1.8) | A (2.9, 2.0) / B (2.0, 1.8, 1.5) / C (1.8, 1.4) | B (2.0) / C (1.0) | B (2.0) / C (1.0) / D (0.9) | B (1.4, 2.0) / C (1.2) / D (0.7) | D (0.7) | |
| 22 | B (2.0, 1.5) | B (1.5) / C (1.5, 1.1) | B (1.9) / C (0.8, 1.0) / D (0.8) | C (1.0) / D (0.7) | D (0.6) | D (0.3, 0.6) / E (0.5) | |
| 33 | B (1.9, 1.7) | B (1.9, 1.4) / D (0.8) | C (0.9, 0.6) / D (0.6) | D (0.6) | D (0.5) | | |
| 47 | B (1.8) / C (0.8) | B (1.8) / C (0.8, 0.5) / D (0.6) | C (0.8, 0.6) / D (0.6) | D (0.7) / E (0.6) | E (0.6) | | |
| 68 | B (1.8) | C (1.0, 0.8) / D (1.0, 0.6, 0.4) | D (0.6) | E (0.6) | | | |
| 100 | E (0.3) | C (0.9, 0.5) / D (0.6) | D (0.6) / E (0.6, 0.15) | | | | |
| 150 | | D (0.6) | | | | | |
| 220 | | E (0.5) | | | | | |

Note

• ESR limits in Ω are shown in parenthesis



Marking

Capacitor marking includes an anode (+) polarity band, capacitance in microfarads and the voltage rating. "A" case capacitors use a letter code for the voltage and EIA capacitance code.

The Vishay identification marking is included if space permits. Vishay marking ("circled 2") may show additives in the form of short lines, depicting actual manufacturing facility. For A case capacitors discontinuation in polarity bar maybe used as actual manufacturing facility designation. Capacitors rated at 6.3 V are marked 6 V.

A manufacturing date code is marked on all capacitors. for details see FAQ: www.vishay.com/doc?40110.

Call the factory for further explanation.

| CAPACITANCE (µF) | CASE CODE | PART NUMBER | MAX. DCL AT +25 °C (μA) | MAX. DF AT +25 °C (%) | MAX. ESR AT +25 °C 100 kHz (Ω) | MAX. RIPPLE 100 kHz I _{RMS} (A) |
|---------------------|-----------|--|--------------------------------|-----------------------------|---|---|
| | | 6.3 V _{DC} AT +85 °C; 4 V _{DC} A | T +125 °C; 3.15 V _I | _{DC} AT +150 °C | | |
| 10 | Α | TH3A106(1)6R3(3)3400 | 0.6 | 6 | 3.40 | 0.15 |
| 10 | Α | TH3A106(1)6R3(3)2700 | 0.6 | 6 | 2.70 | 0.17 |
| 15 | В | TH3B156(1)6R3(2)1800 | 0.9 | 6 | 1.80 | 0.22 |
| 22 | В | TH3B226(1)6R3(2)2000 | 1.3 | 6 | 2.00 | 0.21 |
| 22 | В | TH3B226(1)6R3(2)1500 | 1.3 | 6 | 1.50 | 0.24 |
| 33 | В | TH3B336(1)6R3(2)1900 | 2.0 | 6 | 1.90 | 0.21 |
| 33 | В | TH3B336(1)6R3(2)1700 | 2.0 | 6 | 1.70 | 0.22 |
| 47 | В | TH3B476(1)6R3(2)1800 | 2.8 | 8 | 1.80 | 0.22 |
| 47 | С | TH3C476(1)6R3(3)0800 | 2.8 | 6 | 0.80 | 0.37 |
| 68 | В | TH3B686(1)6R3(2)1800 | 4.1 | 6 | 1.80 | 0.22 |
| 100 | Е | TH3E107(1)6R3(3)0300 | 6.0 | 6 | 0.30 | 0.74 |
| | | 10 V _{DC} AT +85 °C; 7 V _{DC} | AT +125 °C; 5 V _{DC} | AT +150 °C | | |
| 2.2 | Α | TH3A225(1)010(3)4600 | 0.5 | 6 | 4.60 | 0.13 |
| 4.7 | Α | TH3A475(1)010(3)2900 | 0.5 | 6 | 2.90 | 0.16 |
| 4.7 | В | TH3B475(1)010(2)2700 | 0.5 | 6 | 2.70 | 0.18 |
| 6.8 | Α | TH3A685(1)010(3)2600 | 6.8 | 6 | 2.60 | 0.17 |
| 10 | Α | TH3A106(1)010(3)3400 | 1.0 | 6 | 3.40 | 0.15 |
| 10 | Α | TH3A106(1)010(3)2000 | 1.0 | 6 | 2.00 | 0.19 |
| 10 | В | TH3B106(1)010(2)1800 | 1.0 | 6 | 1.80 | 0.22 |
| 10 | С | TH3C106(1)010(3)1800 | 1.0 | 6 | 1.80 | 0.25 |
| 10 | С | TH3C106(1)010(3)1700 | 1.0 | 6 | 1.70 | 0.25 |
| 15 | Α | TH3A156(1)010(3)2900 | 1.0 | 6 | 2.90 | 0.16 |
| 15 | Α | TH3A156(1)010(3)2000 | 1.0 | 6 | 2.00 | 0.19 |
| 15 | В | TH3B156(1)010(2)2000 | 1.0 | 6 | 2.00 | 0.21 |
| 15 | В | TH3B156(1)010(2)1800 | 1.0 | 6 | 1.80 | 0.22 |
| 15 | В | TH3B156(1)010(2)1500 | 1.0 | 6 | 1.50 | 0.24 |
| 15 | С | TH3C156(1)010(3)1800 | 1.0 | 6 | 1.80 | 0.25 |
| 15 | С | TH3C156(1)010(3)1400 | 1.0 | 6 | 1.40 | 0.28 |

- Part number definitions:
 - (1) Capacitance tolerance: K, M
 - (2) Termination and packaging: C, D, E, F, V, U, T, W
 - (3) Termination and packaging: A, B, C, D, E, F, V, U, T, W

| | RATINGS | | | | MAX. ESR | MAX. RIPPLE |
|---------------------|-----------|--|-------------------------------|-----------------------------|-----------------------------|------------------------------------|
| CAPACITANCE (μF) | CASE CODE | PART NUMBER | MAX. DCL AT +25 °C (μA) | MAX. DF AT +25 °C (%) | AT +25 °C 100 kHz (Ω) | 100 kHz I _{RMS} (A) |
| | | 10 V _{DC} AT +85 °C; 7 V _{DC} | AT +125 °C; 5 V _{DC} | AT +150 °C | | |
| 22 | В | TH3B226(1)010(2)1500 | 2.2 | 6 | 1.50 | 0.24 |
| 22 | С | TH3C226(1)010(3)1500 | 2.2 | 6 | 1.50 | 0.27 |
| 22 | C | TH3C226(1)010(3)1100 | 2.2 | 6 | 1.10 | 0.32 |
| 33 | В | TH3B336(1)010(2)1900 | 3.3 | 6 | 1.90 | 0.21 |
| 33 | В | TH3B336(1)010(2)1400 | 3.3 | 6 | 1.40 | 0.25 |
| 33 | D | TH3D336(1)010(3)0800 | 3.3 | 6 | 0.80 | 0.43 |
| 47 | В | TH3B476(1)010(2)1800 | 4.7 | 6 | 1.80 | 0.22 |
| 47 | C | TH3C476(1)010(3)0800 | 4.7 | 6 | 0.80 | 0.37 |
| 47 | C | TH3C476(1)010(3)0500 | 4.7 | 6 | 0.50 | 0.47 |
| 47 | D | TH3D476(1)010(3)0600 | 4.7 | 6 | 0.60 | 0.50 |
| 68 | C | TH3C686(1)010(3)1000 | 6.8 | 8 | 1.00 | 0.33 |
| 68 | C | TH3C686(1)010(3)0800 | 6.8 | 8 | 0.80 | 0.37 |
| 68 | D | TH3D686(1)010(3)1000 | 6.8 | 6 | 1.00 | 0.39 |
| 68 | D | TH3D686(1)010(3)1600 | 6.8 | 6 | 0.60 | 0.50 |
| 68 | D | TH3D686(1)010(3)0400 | 6.8 | 6 | 0.40 | 0.61 |
| 100 | C | | 10.0 | 6 | 0.90 | 0.35 |
| 100 | C | TH3C107(1)010(3)0900 | 10.0 | 6 | 0.50 | 0.33 |
| | | TH3C107(1)010(3)0500 | | | | |
| 100 | D | TH3D107(1)010(3)0600 | 10.0 | 8 | 0.60 | 0.50 |
| 150 | D | TH3D157(1)010(3)0600 | 15.0 | 8 | 0.60 | 0.50 |
| 220 | E | TH3E227(1)010(3)0500 | 22.0 | 8 | 0.50 | 0.61 |
| | | 16 V _{DC} AT +85 °C; 10 V _{DC} | | - | | |
| 1.0 | A | TH3A105(1)016(3)6500 | 0.5 | 4 | 6.50 | 0.11 |
| 2.2 | Α | TH3A225(1)016(3)4300 | 0.5 | 6 | 4.30 | 0.13 |
| 3.3 | A | TH3A335(1)016(3)3400 | 0.5 | 6 | 3.40 | 0.15 |
| 3.3 | В | TH3B335(1)016(2)3000 | 0.5 | 6 | 3.00 | 0.17 |
| 4.7 | Α | TH3A475(1)016(3)2900 | 0.8 | 6 | 2.90 | 0.16 |
| 4.7 | В | TH3B475(1)016(2)2100 | 0.8 | 6 | 2.10 | 0.2 |
| 6.8 | Α | TH3A685(1)016(3)2600 | 1.1 | 6 | 2.60 | 0.17 |
| 6.8 | Α | TH3A685(1)016(3)2000 | 1.1 | 6 | 2.00 | 0.19 |
| 6.8 | В | TH3B685(1)016(2)1800 | 1.1 | 6 | 1.80 | 0.22 |
| 6.8 | С | TH3C685(1)016(3)1700 | 1.1 | 6 | 1.70 | 0.25 |
| 10 | В | TH3B106(1)016(2)2000 | 1.6 | 6 | 2.00 | 0.21 |
| 10 | С | TH3C106(1)016(3)1400 | 1.6 | 6 | 1.40 | 0.28 |
| 10 | С | TH3C106(1)016(3)0800 | 1.6 | 6 | 0.80 | 0.37 |
| 15 | В | TH3B156(1)016(2)2000 | 2.4 | 6 | 2.00 | 0.21 |
| 15 | С | TH3C156(1)016(3)1000 | 2.4 | 6 | 1.00 | 0.33 |
| 22 | В | TH3B226(1)016(2)1900 | 3.5 | 6 | 1.90 | 0.21 |
| 22 | С | TH3C226(1)016(3)1000 | 3.5 | 6 | 1.00 | 0.33 |
| 22 | С | TH3C226(1)016(3)0800 | 3.5 | 4.5 | 0.80 | 0.37 |
| 22 | D | TH3D226(1)016(3)0800 | 3.5 | 6 | 0.80 | 0.43 |
| 33 | С | TH3C336(1)016(3)0900 | 5.3 | 6 | 0.90 | 0.35 |
| 33 | С | TH3C336(1)016(3)0600 | 5.3 | 6 | 0.60 | 0.43 |
| 33 | D | TH3D336(1)016(3)0600 | 5.3 | 6 | 0.60 | 0.50 |
| 47 | C | TH3C476(1)016(3)0800 | 7.5 | 6 | 0.80 | 0.37 |
| 47 | C | TH3C476(1)016(3)0600 | 7.5 | 6 | 0.60 | 0.43 |
| 47 | D | TH3D476(1)016(3)0600 | 7.5 | 6 | 0.60 | 0.43 |
| 68 | D | TH3D686(1)016(3)0600 | 10.9 | 6 | 0.60 | 0.50 |
| 100 | D | TH3D107(1)016(3)0600 | 16.0 | 8 | 0.60 | 0.50 |
| 100 | E | TH3E107(1)016(3)0600 | 16.0 | 8 | 0.60 | 0.56 |
| 100 | E | TH3E107(1)016(3)0150 | 16.0 | 8 | 0.15 | 1.11 |

- Part number definitions:
 - (1) Capacitance tolerance: K, M

 - (2) Termination and packaging: C, D, E, F, V, U, T, W
 (3) Termination and packaging: A, B, C, D, E, F, V, U, T, W



| STANDARD | na i ingo | | | | MAY FOR | MAY DIDD! |
|---------------------|-----------|--|-------------------------------|-----------------------------|---|---|
| CAPACITANCE (μF) | CASE CODE | PART NUMBER | MAX. DCL AT +25 °C (μA) | MAX. DF AT +25 °C (%) | MAX. ESR AT +25 °C 100 kHz (Ω) | MAX. RIPPLE 100 kHz I _{RMS} (A) |
| | | 20 V _{DC} AT +85 °C; 13 V _{DC} | AT +125 °C; 10 V _D | OC AT +150 °C | | |
| 1.0 | Α | TH3A105(1)020(3)5900 | 0.5 | 4 | 5.90 | 0.11 |
| 2.2 | Α | TH3A225(1)020(3)5900 | 0.5 | 6 | 5.90 | 0.11 |
| 2.2 | В | TH3B225(1)020(2)3500 | 0.5 | 6 | 3.50 | 0.16 |
| 3.3 | В | TH3B335(1)020(2)2700 | 0.7 | 6 | 2.70 | 0.18 |
| 3.3 | С | TH3C335(1)020(3)2700 | 0.7 | 6 | 2.70 | 0.20 |
| 4.7 | Α | TH3A475(1)020(3)5000 | 0.9 | 6 | 5.00 | 0.12 |
| 4.7 | В | TH3B475(1)020(2)1900 | 0.9 | 6 | 2.90 | 0.17 |
| 4.7 | В | TH3B475(1)020(2)2900 | 0.9 | 6 | 1.90 | 0.21 |
| 4.7 | С | TH3C475(1)020(3)1700 | 0.9 | 6 | 1.70 | 0.25 |
| 10 | С | TH3C106(1)020(3)1100 | 2.0 | 6 | 1.10 | 0.32 |
| 15 | В | TH3B156(1)020(2)2000 | 3.0 | 6 | 2.00 | 0.21 |
| 15 | С | TH3C156(1)020(3)1000 | 3.0 | 6 | 1.00 | 0.33 |
| 15 | D | TH3D156(1)020(3)0900 | 3.0 | 6 | 0.90 | 0.41 |
| 22 | С | TH3C226(1)020(3)1000 | 4.4 | 6 | 1.00 | 0.33 |
| 22 | D | TH3D226(1)020(3)0700 | 4.4 | 6 | 0.70 | 0.46 |
| 33 | D | TH3D336(1)020(3)0600 | 6.6 | 6 | 0.60 | 0.5 |
| 47 | D | TH3D476(1)020(3)0700 | 9.4 | 6 | 0.70 | 0.46 |
| 47 | E | TH3E476(1)020(3)0600 | 9.4 | 8 | 0.60 | 0.56 |
| 68 | Е | TH3E686(1)020(3)0600 | 13.6 | 8 | 0.60 | 0.56 |
| | | 25 V _{DC} AT +85 °C; 17 V _{DC} | AT +125 °C; 12.5 V | _{DC} AT +150 °C | | |
| 0.47 | Α | TH3A474(1)025(3)14R0 | 0.5 | 4 | 14.00 | 0.073 |
| 1.0 | Α | TH3A105(1)025(3)5200 | 0.5 | 4 | 5.20 | 0.12 |
| 1.0 | Α | TH3A105(1)025(3)3000 | 0.5 | 4 | 3.00 | 0.16 |
| 1.0 | В | TH3B105(1)025(2)5000 | 0.5 | 4 | 5.00 | 0.13 |
| 2.2 | Α | TH3A225(1)025(3)5200 | 0.6 | 6 | 5.20 | 0.12 |
| 2.2 | В | TH3B225(1)025(2)3000 | 0.6 | 6 | 3.00 | 0.17 |
| 3.3 | В | TH3B335(1)025(2)3000 | 0.8 | 6 | 3.00 | 0.17 |
| 3.3 | С | TH3C335(1)025(3)2000 | 0.8 | 6 | 2.00 | 0.23 |
| 4.7 | Α | TH3A475(1)025(3)5000 | 1.2 | 6 | 5.00 | 0.12 |
| 4.7 | В | TH3B475(1)025(2)2800 | 1.2 | 6 | 2.80 | 0.17 |
| 4.7 | С | TH3C475(1)025(3)1600 | 1.2 | 6 | 1.60 | 0.26 |
| 6.8 | В | TH3B685(1)025(2)2400 | 1.7 | 6 | 2.40 | 0.19 |
| 6.8 | С | TH3C685(1)025(3)1400 | 1.7 | 6 | 1.40 | 0.28 |
| 10 | С | TH3C106(1)025(3)1100 | 2.5 | 6 | 1.10 | 0.32 |
| 10 | D | TH3D106(1)025(3)0900 | 2.5 | 6 | 0.90 | 0.41 |
| 15 | В | TH3B156(1)025(2)2000 | 3.8 | 6 | 2.00 | 0.21 |
| 15 | В | TH3B156(1)025(2)1400 | 3.8 | 6 | 1.40 | 0.25 |
| 15 | С | TH3C156(1)025(3)1200 | 3.8 | 6 | 1.20 | 0.30 |
| 15 | D | TH3D156(1)025(3)0700 | 3.8 | 6 | 0.70 | 0.46 |
| 22 | D | TH3D226(1)025(3)0600 | 5.5 | 6 | 0.60 | 0.50 |
| 33 | D | TH3D336(1)025(3)0500 | 8.3 | 6 | 0.50 | 0.55 |
| 47 | Е | TH3E476(1)025(3)0600 | 11.8 | 6 | 0.60 | 0.56 |

- Part number definitions:
 - (1) Capacitance tolerance: K, M

 - (2) Termination and packaging: C, D, E, F, V, U, T, W
 (3) Termination and packaging: A, B, C, D, E, F, V, U, T, W



Vishay Sprague

| STANDARD | RATINGS | | | | | |
|---------------------|-----------|--|-------------------------------|-----------------------------|---|---|
| CAPACITANCE (μF) | CASE CODE | PART NUMBER | MAX. DCL AT +25 °C (μA) | MAX. DF AT +25 °C (%) | MAX. ESR AT +25 °C 100 kHz (Ω) | MAX. RIPPLE 100 kHz I _{RMS} (A) |
| | | 35 V _{DC} AT +85 °C; 23 V _{DC} A | AT +125 °C; 17.5 V | _{DC} AT +150 °C | | |
| 0.33 | Α | TH3A334(1)035(3)11R0 | 0.5 | 4 | 11.00 | 0.08 |
| 1.0 | Α | TH3A105(1)035(3)6600 | 0.5 | 4 | 6.60 | 0.11 |
| 1.0 | В | TH3B105(1)035(2)4400 | 0.5 | 4 | 4.40 | 0.14 |
| 1.5 | В | TH3B155(1)035(2)4200 | 0.5 | 6 | 4.20 | 0.14 |
| 1.5 | С | TH3C155(1)035(3)3300 | 0.5 | 6 | 3.30 | 0.18 |
| 2.2 | В | TH3B225(1)035(2)2500 | 0.8 | 6 | 2.50 | 0.18 |
| 2.2 | С | TH3C225(1)035(3)2200 | 0.8 | 6 | 2.20 | 0.22 |
| 3.3 | В | TH3B335(1)035(2)3500 | 1.2 | 6 | 3.50 | 0.16 |
| 3.3 | В | TH3B335(1)035(2)2500 | 1.2 | 6 | 2.50 | 0.18 |
| 3.3 | С | TH3C335(1)035(3)1700 | 1.2 | 6 | 1.70 | 0.25 |
| 4.7 | В | TH3B475(1)035(2)3100 | 1.7 | 6 | 3.10 | 0.17 |
| 4.7 | С | TH3C475(1)035(3)1300 | 1.6 | 6 | 1.30 | 0.29 |
| 4.7 | D | TH3D475(1)035(3)1000 | 1.6 | 6 | 1.00 | 0.39 |
| 6.8 | С | TH3C685(1)035(3)1800 | 2.4 | 6 | 1.80 | 0.25 |
| 6.8 | D | TH3D685(1)035(3)0900 | 2.4 | 6 | 0.90 | 0.41 |
| 10 | С | TH3C106(1)035(3)1600 | 3.5 | 6 | 1.60 | 0.26 |
| 10 | D | TH3D106(1)035(3)0700 | 3.5 | 6 | 0.70 | 0.46 |
| 10 | D | TH3D106(1)035(3)0300 | 3.5 | 6 | 0.30 | 0.71 |
| 10 | D | TH3D106(1)035(3)0250 | 3.5 | 6 | 0.25 | 0.77 |
| 15 | D | TH3D156(1)035(3)0700 | 5.3 | 6 | 0.70 | 0.46 |
| 22 | D | TH3D226(1)035(3)0600 | 7.7 | 6 | 0.60 | 0.50 |
| 22 | D | TH3D226(1)035(3)0300 | 7.7 | 6 | 0.30 | 0.71 |
| 22 | E | TH3E226(1)035(3)0500 | 7.7 | 6 | 0.50 | 0.61 |
| | | 50 V _{DC} AT +85 °C; 33 V _{DC} | AT +125 °C; 25 V _D | _C AT +150 °C | | |
| 1.0 | С | TH3C105(1)050(3)3300 | 0.5 | 4 | 3.30 | 0.18 |
| 3.3 | D | TH3D335(1)050(3)1700 | 1.7 | 6 | 1.70 | 0.30 |
| 4.7 | С | TH3C475(1)050(3)1500 | 2.4 | 6 | 1.50 | 0.27 |
| 4.7 | D | TH3D475(1)050(3)0900 | 2.4 | 6 | 0.90 | 0.41 |
| 6.8 | D | TH3D685(1)050(3)0900 | 3.4 | 6 | 0.90 | 0.41 |
| 10 | D | TH3D106(1)050(3)0800 | 5.0 | 6 | 0.80 | 0.43 |
| 10 | Е | TH3E106(1)050(3)0500 | 5.0 | 6 | 0.50 | 0.61 |

- Part number definitions:
 - (1) Capacitance tolerance: K, M
- (2) Termination and packaging: C, D, E, F, V, U, T, W
 (3) Termination and packaging: A, B, C, D, E, F, V, U, T, W

| POWER DISSIPATION | POWER DISSIPATION | | | | | | |
|-------------------|---|--|--|--|--|--|--|
| CASE CODE | MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 °C (W) IN FREE AIR | | | | | | |
| A | 0.075 | | | | | | |
| В | 0.085 | | | | | | |
| С | 0.110 | | | | | | |
| D | 0.150 | | | | | | |
| E | 0.165 | | | | | | |



| STANDARD PACKAGING QUANTITY | | | | |
|-----------------------------|---------|----------|--|--|
| CASE CODE | UNITS P | PER REEL | | |
| CASE CODE | 7" REEL | 13" REEL | | |
| A | 2000 | 9000 | | |
| В | 2000 | 8000 | | |
| С | 500 | 3000 | | |
| D | 500 | 2500 | | |
| E | 400 | 1500 | | |

| PRODUCT INFORMATION | | | | |
|--------------------------------------|--------------------------|--|--|--|
| Guide for Molded Tantalum Capacitors | | | | |
| Pad Dimensions | www.vishay.com/doc?40074 | | | |
| Package Dimensions | | | | |
| Moisture Sensitivity (MSL) | www.vishay.com/doc?40135 | | | |
| SELECTOR GUIDES | | | | |
| Solid Tantalum Selector Guide | www.vishay.com/doc?49053 | | | |
| Solid Tantalum Chip Capacitors | www.vishay.com/doc?40091 | | | |
| FAQ | | | | |
| Frequently Asked Questions | www.vishay.com/doc?40110 | | | |



Guide for Molded Tantalum Capacitors

INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Revision: 13-Dec-2018

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

| COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS | | | | |
|--|--------------------------|--|--|--|
| DIELECTRIC | e DIELECTRIC CONSTANT | | | |
| Air or vacuum | 1.0 | | | |
| Paper | 2.0 to 6.0 | | | |
| Plastic | 2.1 to 6.0 | | | |
| Mineral oil | 2.2 to 2.3 | | | |
| Silicone oil | 2.7 to 2.8 | | | |
| Quartz | 3.8 to 4.4 | | | |
| Glass | 4.8 to 8.0 | | | |
| Porcelain | 5.1 to 5.9 | | | |
| Mica | 5.4 to 8.7 | | | |
| Aluminum oxide | 8.4 | | | |
| Tantalum pentoxide | 26 | | | |
| Ceramic | 12 to 400K | | | |

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.



Vishay Sprague

SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the leadframe.

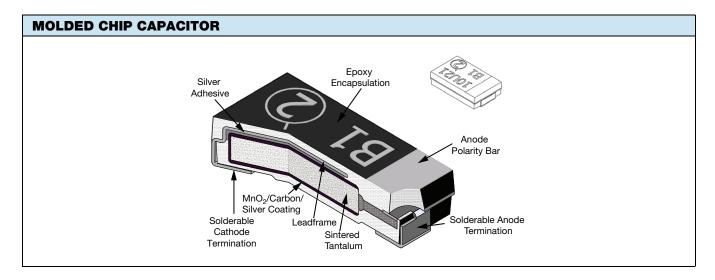
Molded Chip tantalum capacitor encases the element in plastic resins, such as epoxy materials. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost

Surface mount designs of "Solid Tantalum" capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.







COMMERCIAL PRODUCTS

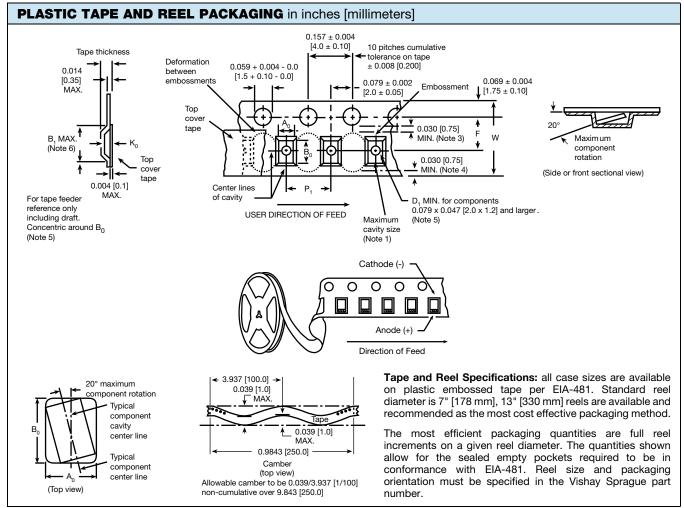
| SOLID TANTALUM CAPACITORS - MOLDED CASE | | | | | | | |
|---|---|--|--------------------|---------------------------|---------------------------------------|--|--|
| SERIES | 293D | 793DX-CTC3- CTC4 | 593D | TR3 | TP3 | TL3 | |
| PRODUCT IMAGE | IN THE REAL PROPERTY. | In the line (1878) | \$\$ ********* | | 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 | 18 0 15 0 | |
| TYPE | | Surface mount TANTAMOUNT™, molded case | | | | | |
| FEATURES | Standard industrial grade | CECC approved | Low ESR | Low ESR | High performance, automotive grade | Very low DCL | |
| TEMPERATURE RANGE | | | -55 °(| C to +125 °C | | | |
| CAPACITANCE RANGE | 0.1 μF to 1000 μF | 0.1 μF to 100 μF | 1 μF to 470 μF | 0.47 μF to 1000 μF | 0.1 μF to 470 μF | 0.1 μF to 470 μF | |
| VOLTAGE RANGE | 4 V to 75 V | 4 V to 50 V | 4 V to 50 V | 4 V to 75 V | 4 V to 50 V | 4 V to 50 V | |
| CAPACITANCE TOLERANCE | | ± 10 %, ± 20 % | | | | | |
| LEAKAGE CURRENT | 0.01 CV or 0.5 μA, whichever is greater | | | | | 0.005 CV or 0.25 µA, whichever is greater | |
| DISSIPATION FACTOR | 4 % to 30 % | 4 % to 6 % | 4 % to 15 % | 4 % to 30 % | 4 % to 15 % | 4 % to 15 % | |
| CASE CODES | A, B, C, D, E | A, B, C, D | A, B, C, D, E | A, B, C, D, E, W | A, B, C, D, E | A, B, C, D, E | |
| TERMINATION | | 10 | 00 % matte tin sta | andard, tin / lead availa | ble | | |

| SOLID TANTAL | SOLID TANTALUM CAPACITORS - MOLDED CASE | | | | | | |
|--------------------------|---|---|-------------------------------|--|--|--|--|
| SERIES | тнз | TH4 | TH5 | | | | |
| PRODUCT IMAGE | | Maria Salanda | Torse | | | | |
| TYPE | Sur | face mount TANTAMOUNT™, molded o | case | | | | |
| FEATURES | High temperature +150 °C, automotive grade | High temperature +175 °C, automotive grade | Very high temperature +200 °C | | | | |
| TEMPERATURE RANGE | -55 °C to +150 °C | -55 °C to +175 °C | -55 °C to +200 °C | | | | |
| CAPACITANCE RANGE | 0.33 μF to 220 μF | 10 μF to 100 μF | 4.7 μF to 100 μF | | | | |
| VOLTAGE RANGE | 6.3 V to 50 V | 6.3 V to 35 V | 5 V to 24 V | | | | |
| CAPACITANCE TOLERANCE | | ± 10 %, ± 20 % | | | | | |
| LEAKAGE CURRENT | 0.01 CV or 0.5 μA, whichever is greater | | | | | | |
| DISSIPATION FACTOR | 4 % to 8 % | 4.5 % to 8 % | 6 % to 10 % | | | | |
| CASE CODES | A, B, C, D, E | B, C, D, E | D, E | | | | |
| TERMINATION | 100 % matte tin standard, tin / lead and gold plated available | 100 % matte tin | Gold plated | | | | |



HIGH RELIABILITY PRODUCTS

| SOLID TANTALUM CAPACITORS - MOLDED CASE | | | | | | |
|---|--|--|--|--|--|--|
| SERIES | ТМ3 | T83 | CWR11 | 95158 | | |
| PRODUCT IMAGE | The same of the sa | 47716 70 3 | | | | |
| TYPE TANTAMOUNT TM , molded case, hi-rel. TANTAMOUNT TM , molded case, hi-rel. COTS | | Tantamount™ DLA ap | | | | |
| FEATURES | High reliability, for medical Instruments | High reliability, standard and low ESR | MIL-PRF-55365/8 qualified | Low ESR | | |
| TEMPERATURE RANGE | | -55 °C to +125 °C | | | | |
| CAPACITANCE RANGE | 1 μF to 220 μF | 0.1 μF to 470 μF | 0.1 μF to 100 μF | 4.7 μF to 220 μF | | |
| VOLTAGE RANGE | 4 V to 20 V | 4 V to 63 V | 4 V to | 50 V | | |
| CAPACITANCE TOLERANCE | ± 10 %, ± 2 | 20 % | ± 5 %, ± 10 %, ± 20 % | ± 10 %, ± 20 % | | |
| LEAKAGE CURRENT | 0.005 CV or 0.25 μA, whichever is greater | 0.0 | 1 CV or 0.5 μA, whichever is g | reater | | |
| DISSIPATION FACTOR | 4 % to 8 % | 4 % to 15 % | 4 % to 6 % | 4 % to 12 % | | |
| CASE CODES | A, B, C, D, E | A, B, C, D, E | A, B, C, D | C, D, E | | |
| TERMINATION | 100 % matte tin; tin / lead | 100 % matte tin; tin / lead; tin / lead solder fused | Tin / lead; tin / lead solder fused | Tin / lead solder plated; gold plated | | |



Notes

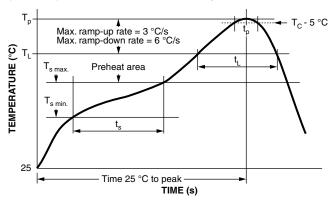
- Metric dimensions will govern. Dimensions in inches are rounded and for reference only.
- (1) A₀, B₀, K₀, are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A₀, B₀, K₀) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°.
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum.
- (3) This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less.
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less.
- (5) The embossed hole location shall be measured from the sprocket hole controlling the location of the embossement. Dimensions of embossement location shall be applied independent of each other.
- (6) B₁ dimension is a reference dimension tape feeder clearance only.

| CASE CODE | TAPE SIZE | B ₁ (MAX.) | D ₁ (MIN.) | F | K ₀ (MAX.) | P ₁ | w |
|--------------|--------------|--------------------------|--------------------------|------------------|--------------------------|-------------------|-------------------|
| MOLDED | CHIP CAPA | CITORS; ALL TY | PES | | | | |
| Α | 8 mm | 0.165 | 0.039 | 0.138 ± 0.002 | 0.094 | 0.157 ± 0.004 | 0.315 ± 0.012 |
| В | 0 111111 | [4.2] | [1.0] | $[3.5 \pm 0.05]$ | [2.4] | $[4.0 \pm 1.0]$ | $[8.0 \pm 0.30]$ |
| С | | | | | | | |
| D | 12 mm | 0.32 | 0.059 | 0.217 ± 0.00 | 0.177 | 0.315 ± 0.004 | 0.472 ± 0.012 |
| E | 12 111111 | [8.2] | [1.5] | $[5.5 \pm 0.05]$ | [4.5] | $[8.0 \pm 1.0]$ | $[12.0 \pm 0.30]$ |
| W | | | | | | | |



RECOMMENDED REFLOW PROFILES

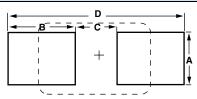
Capacitors should withstand reflow profile as per J-STD-020 standard, three cycles.



| PROFILE FEATURE | SnPb EUTECTIC ASSEMBLY | LEAD (Pb)-FREE ASSEMBLY | |
|--|--|-------------------------|--|
| Preheat / soak | | | |
| Temperature min. (T _{s min.}) | 100 °C | 150 °C | |
| Temperature max. (T _{s max.}) | 150 °C | 200 °C | |
| Time (t _s) from (T _{s min.} to T _{s max.}) | 60 s to 120 s | 60 s to 120 s | |
| Ramp-up | | | |
| Ramp-up rate (T _L to T _p) | 3 °C/s max. | 3 °C/s max. | |
| Liquidus temperature (T _L) | 183 °C | 217 °C | |
| Time (t _L) maintained above T _L | 60 s to 150 s | 60 s to 150 s | |
| Peak package body temperature (Tp) | Depends on case size - see table below | | |
| Time (t _p) within 5 °C of the specified classification temperature (T _C) | 20 s | 30 s | |
| Time 25 °C to peak temperature | 6 min max. | 8 min max. | |
| Ramp-down | | | |
| Ramp-down rate (T _p to T _L) | 6 °C/s max. | 6 °C/s max. | |

| PEAK PACKAGE BODY TEMPERATURE (T _p) | | | | |
|---|------------------------------------|------------------------|--|--|
| CASE CODE | PEAK PACKAGE BODY TEMPERATURE (Tp) | | | |
| CASE CODE | SnPb EUTECTIC PROCESS | LEAD (Pb)-FREE PROCESS | | |
| A, B, C | 235 °C | 260 °C | | |
| D, E, W | 220 °C | 250 °C | | |

PAD DIMENSIONS in inches [millimeters]



| CASE CODE | A (MIN.) | B (NOM.) | C (NOM.) | D (NOM.) |
|---------------------|-----------------|--------------|--------------|--------------|
| MOLDED CHIP CAPACIT | TORS, ALL TYPES | | | |
| Α | 0.071 [1.80] | 0.067 [1.70] | 0.053 [1.35] | 0.187 [4.75] |
| В | 0.118 [3.00] | 0.071 [1.80] | 0.065 [1.65] | 0.207 [5.25] |
| С | 0.118 [3.00] | 0.094 [2.40] | 0.118 [3.00] | 0.307 [7.80] |
| D | 0.157 [4.00] | 0.098 [2.50] | 0.150 [3.80] | 0.346 [8.80] |
| E | 0.157 [4.00] | 0.098 [2.50] | 0.150 [3.80] | 0.346 [8.80] |
| W | 0.185 [4.70] | 0.098 [2.50] | 0.150 [3.80] | 0.346 [8.80] |

Vishay Sprague

GUIDE TO APPLICATION

 AC Ripple Current: the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).

R_{ESR} = the capacitor equivalent series resistance at the specified frequency

2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

or, from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

where.

P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).

R_{ESR} = the capacitor equivalent series resistance at the specified frequency

Z = the capacitor impedance at the specified frequency

- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at +25 °C.
- 3. **Reverse Voltage:** solid tantalum capacitors are not intended for use with reverse voltage applied. However, they have been shown to be capable of withstanding momentary reverse voltage peaks of up to 10 % of the DC rating at 25 °C and 5 % of the DC rating at +85 °C.
- 4. Temperature Derating: if these capacitors are to be operated at temperatures above +25 °C, the permissible RMS ripple current shall be calculated using the derating factors as shown:

| TEMPERATURE (°C) | DERATING FACTOR |
|---------------------|-----------------|
| +25 | 1.0 |
| +85 | 0.9 |
| +125 | 0.4 |
| +150 ⁽¹⁾ | 0.3 |
| +175 ⁽¹⁾ | 0.2 |
| +200 (1) | 0.1 |

Note

(1)Applicable for dedicated high temperature product series

5. **Power Dissipation:** power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I_{RMS} value

be established when calculating permissible operating levels. (Power dissipation calculated using +25 °C temperature rise).

 Printed Circuit Board Materials: molded capacitors are compatible with commonly used printed circuit board materials (alumina substrates, FR4, FR5, G10, PTFE-fluorocarbon and porcelanized steel).

7. Attachment:

- 7.1 **Solder Paste:** the recommended thickness of the solder paste after application is 0.007" ± 0.001" [0.178 mm ± 0.025 mm]. Care should be exercised in selecting the solder paste. The metal purity should be as high as practical. The flux (in the paste) must be active enough to remove the oxides formed on the metallization prior to the exposure to soldering heat. In practice this can be aided by extending the solder preheat time at temperatures below the liquidous state of the solder.
- 7.2 **Soldering:** capacitors can be attached by conventional soldering techniques; vapor phase, convection reflow, infrared reflow, wave soldering, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 2 °C per s. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor.
- 7.2.1 Backward and Forward Compatibility: capacitors with SnPb or 100 % tin termination finishes can be soldered using SnPb or lead (Pb)-free soldering processes.
- 8. Cleaning (Flux Removal) After Soldering: molded capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chlorethane, Terpene and aqueous cleaning media. However, CFC / ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.
- 8.1 When using ultrasonic cleaning, the board may resonate if the output power is too high. This vibration can cause cracking or a decrease in the adherence of the termination. DO NOT EXCEED 9W/I at 40 kHz for 2 min.
- 9. Recommended Mounting Pad Geometries: proper mounting pad geometries are essential for successful solder connections. These dimensions are highly process sensitive and should be designed to minimize component rework due to unacceptable solder joints. The dimensional configurations shown are the recommended pad geometries for both wave and reflow soldering techniques. These dimensions are intended to be a starting point for circuit board designers and may be fine tuned if necessary based upon the peculiarities of the soldering process and / or circuit board design.



Vishay Sprague

Molded Chip Tantalum Capacitors, Automotive Grade

| ELECTRICAL PERFO | RMANCE CHAR | ACTERISTICS | | | |
|---------------------------------------|--|---------------------------------|---|--|----------------------------|
| ITEM | PERFORMANCE CHARACTERISTICS | | | | |
| Category temperature range | $^{-55}$ °C to $_{+85}$ °C (to $_{+175}$ °C with voltage derating - refer to graph "Category Voltage vs. Temperature") $^{(1)}$ | | | | |
| Capacitance tolerance | ± 20 %, ± 10 %, tes | sted via bridge method | l, at 25 °C, 120 Hz | | |
| Dissipation factor | Limits per Standard | Ratings table. Tested | via bridge method, at | t 25 °C, 120 Hz | |
| ESR | | Ratings table. Tested | | | |
| Leakage current | resistor in series wit whichever is greater | h the capacitor under | test, leakage current a e current varies with te | n using a steady source at 25°C is not more tha emperature and applied ate adjustment factor. | in 0.01 CV or 0.5 μA, |
| Capacitance change by temperature | +30 % max. (at +17 +20 % max. (at +12 +10 % max. (at +85 -10 % max. (at -55 | 5 °C and +150 °C) °C) °C) | | | |
| Reverse voltage | Capacitors are capable of withstanding peak voltages in the reverse direction equal to: 10 % of the DC rating at +25 °C 5 % of the DC rating at +85 °C 1 % of the DC rating at +125 °C | | | | |
| Ripple current | For maximum ripple current values (at 25 °C) refer to relevant datasheet. If capacitors are to be used at temperatures above +25 °C, the permissible RMS ripple current (or voltage) shall be calculated using the derating factors: 1.0 at +25 °C 0.9 at +85 °C 0.4 at +125 °C 0.3 at +125 °C 0.2 at +175 °C | | | | |
| Maximum operating | +85 °C | | +125 °C | | +150 °C / +175 °C |
| and surge voltages vs. temperature | RATED VOLTAGE (V) | SURGE VOLTAGE (V) | CATEGORY VOLTAGE (V) | SURGE VOLTAGE (V) | CATEGORY VOLTAGE (V) |
| | 4 | 5.2 | 2.7 | 3.4 | n/a |
| | 6.3 | 8 | 4 | 5 | 3 |
| | 10 | 13 | 7 | 8 | 5 |
| | 16 | 20 | 10 | 12 | 8 |
| | 20 | 26 | 13 | 16 | 10 |
| | 25 | 32 | 17 | 20 | 12.5 |
| | 35 | 46 | 23 | 28 | 17.5 |
| | 50 | 65 | 33 | 40 | 25 |
| | 50 ⁽²⁾ | 60 | 33 | 40 | n/a |
| | 63 | 75 | 42 | 50 | n/a |
| | 75 ⁽³⁾ | 75 | 50 | 50 | n/a |

Notes

- All information presented in this document reflects typical performance characteristics
- (1) Series TH3 up to 150 °C; TH4 up to 175 °C
- (2) Capacitance value 15 µF and higher
- (3) For 293D and TR3 only

| RECOMMENDED VOLTAGE DERATING GUIDELINES (for temperature below +85 °C) | | | | |
|--|----------------------------|--|--|--|
| VOLTAGE RAIL | CAPACITOR VOLTAGE RATING | | | |
| ≤ 3.3 | 6.3 | | | |
| 5 | 10 | | | |
| 10 | 20 | | | |
| 12 | 25 | | | |
| 15 | 35 | | | |
| ≥ 24 | 50 or series configuration | | | |

Note

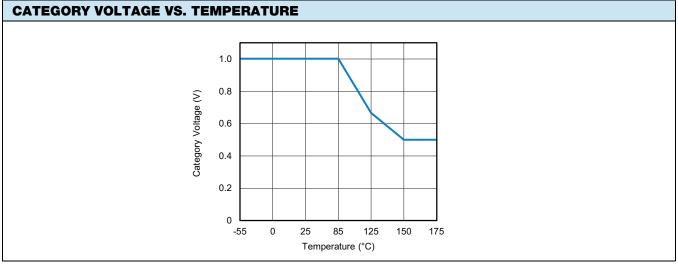
• For temperatures above +85 °C the same voltage derating ratio is recommended, but with respect to category voltage.

Up to +85 °C: category voltage = rated voltage At +125 °C: category voltage = 2/3 of rated voltage

At 150 °C / 175 °C: category voltage = 1/2 of rated voltage

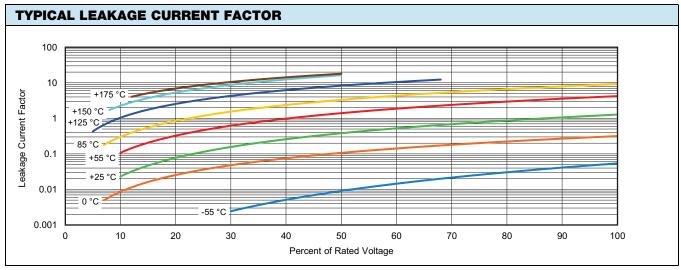
Revision: 07-Feb-2019 1 Document Number: 40215

Vishay Sprague



Note

• Below 85 °C category voltage is equal to rated voltage



- At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table.
 - At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table.
- At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table.
- At +150 °C, the leakage current shall not exceed 15 times the value listed in the Standard Ratings table.
- At +175 °C, the leakage current shall not exceed 18 times the value listed in the Standard Ratings table

Typical Performance Characteristics

Vishay Sprague

| ITEM | CONDITION | POST TEST PERFORMANCE | | |
|--|--|--|--|--|
| High temperature exposure (storage) | MIL-STD-202, method 108 1000 h, at maximum rated temperature, unpowered | Capacitance change Dissipation factor Leakage current ESR | Within ± 20 % of initial value Initial specified limit Initial specified limit Initial specified limit | |
| Operational life test at +125 °C | AEC-Q200 1000 h application 2/3 of rated voltage | Capacitance change Dissipation factor Leakage current ESR | Within ± 20 % of initial value Initial specified limit Shall not exceed 10 times the initial limit Initial specified limit | |
| Operational life test at +150 °C (for TH3) and at +175 °C (for TH4) | AEC-Q200 1000 h application 1/2 of rated voltage | Capacitance change Dissipation factor Leakage current ESR | Within ± 20 % of initial value Shall not exceed 3 times the initial limit Shall not exceed 10 times the initial limit Shall not exceed 3 times the initial limit | |
| Surge voltage | MIL-PRF-55365: 1000 successive test cycles at 85 °C of surge voltage (as specified in the table above), in series with a 33 Ω resistor at the rate of 30 s ON, 30 s OFF | Capacitance change Dissipation factor Leakage current ESR | Within ± 30 % of initial value Shall not exceed 1.5 times the initial limit Shall not exceed 2 times the initial limit Shall not exceed 1.5 times the initial limit | |
| Biased humidity test | AEC-Q200 At 85 °C / 85 % RH, 1000 h, with rated voltage applied | Capacitance change Dissipation factor Leakage current ESR | Within ± 20 % of initial value Shall not exceed 3 times the initial limit Shall not exceed 10 times the initial limit Shall not exceed 3 times the initial limit | |
| Temperature cycling | AEC-Q200 / JESD22, method JA-104 -55 °C / +125 °C, for 1000 cycles | Capacitance change Dissipation factor Leakage current ESR | Within ± 20 % of initial value Initial specified limit Initial specified limit Initial specified limit | |

| MECHANICAL | PERFORMANCE CHARACTERISTICS | |
|---|--|--|
| ITEM | CONDITION | POST TEST PERFORMANCE |
| Vibration | MIL-STD-202, method 204: 10 Hz to 2000 Hz, 5 g peak for 20 min, 12 cycles each of 3 orientations (total 36 cycles), at rated voltage | Capacitance change Within ± 20 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit |
| | | There shall be no mechanical or visual damage to capacitors post-conditioning. |
| Mechanical shock | MIL-STD-202, method 213, condition F, 1500 <i>g</i> peak, 0.5 ms, half-sine | Capacitance change Within ± 20 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit |
| | | There shall be no mechanical or visual damage to capacitors post-conditioning. |
| Resistance to solder heat | MIL-STD-202, method 210, condition D Solder dip 260 °C ± 5 °C, 10 s | Capacitance change Within ± 20 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit |
| Resistance to solvents | MIL-STD-202, method 215 | Capacitance change Within ± 20 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit |
| | | There shall be no mechanical or visual damage to capacitors post-conditioning. Body marking shall remain legible. |
| Solderability | AEC-Q200 / J-STD-002 | Electrical test not required |
| Terminal strength / Shear force test | AEC-Q200-006 Apply a pressure load of 17.7 N (1.8 kg) for 60 s horizontally to the center of capacitor side body Exception: for case size 0603 pressure load is 5N | Part should not be sheared off the pads and no body cracking post-conditioning. Electrical test not required. |
| Flammability | Encapsulation materials meet UL 94 V-0 with an oxygen index of 32 % | n/a |



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.